Pristine carbon nitride as active material for high-performance metal-free supercapacitors: simple, easy and cheap†

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Understanding the basic properties of pristine carbon nitride electrodes is of great importance for their further applications as supercapacitor materials. To this end, a comparative study of unmodified carbon nitride is crucial to understand the difference between the bare material and its composite counterparts described in the literature. Therefore, the aim of this paper is to explore the electrochemical behaviour of casting-produced C3N4 electrodes using cyclic voltammetry, charge/discharge curves and impedance spectroscopy. The results from this study show a capacitance value of 113.7 F g⁻¹ at 0.2 A g⁻¹ with an impressive retention of 89.2% after 5000 charge and discharge cycles at 3.0 A g⁻¹. In addition, this material shows a large amount of specific energy (76.5 W h kg⁻¹) at an operation power of 11.9 W kg⁻¹, decreasing only 10.7% due to the electrochemical aging process. Hence, C3N4 constitutes a long-life pristine material with a large amount of energy and a moderate operation power with better performance than other C3N4-based composites found in the literature. These results are important to gain a better understanding of the inherent properties of carbon nitride – to further design composites with higher specific capacitance, longer lifetime, and specific energy.

1 Introduction

Because of the dramatic increase in the use of fossil fuels and the global concerns about the depletion of natural resources, there has been strong new interest in new renewable energy sources such as wind and solar energy to replace the use of fossil fuels in global energy consumption. Since wind and solar power generation is intermittent and variable, the search for sustainable energy sources such as wind and solar energy is crucial to understand the differences in existing energy storage technologies. It is important to emphasise that organic materials are abundant, cheap, and their synthesis can be designed to produce minimal waste. Furthermore, these materials are very versatile and allow various types of functionalization to improve their properties. Graphene-based supercapacitors are well researched due to interesting properties of graphene oxide (GO) and reduced graphene oxide (rGO). Among them, Wang et al. reported the synthesis of Ni(OH)₂ nanoparticles supported on graphene sheets – this new material showed a surprising capacitance value of 1335 F g⁻¹ at a current density of 2.8 A g⁻¹ with a retention of ~99% after 2000 charge/discharge cycles at 28.6 A g⁻¹. On the other hand, using another synthetic method and bare GO, Lee et al. produced nanoballs of a mesoporous graphene using chemical vapour deposition with a high specific area (508 m² g⁻¹) and this material exhibited a capacitance value of 206 F g⁻¹ with an excellent retention of 97% after 10k cycles. Although graphene has presented such interesting remarks, its synthesis different materials when compared to the conventional ones. Two different kinds of capacitance are expected for supercapacitors: double-layer capacitance and the pseudocapacitance due to an electrochemical reaction. Moreover, supercapacitors are capable of managing high power rates compared to batteries and it is noteworthy to mention that these materials are an attractive and plausible alternative for renewable energy applications in electric vehicles.

Organic materials are very interesting and allow further improvements in existing energy storage technologies. It is important to emphasise that organic materials are abundant, cheap, and their synthesis can be designed to produce minimal waste. Furthermore, these materials are very versatile and allow various types of functionalization to improve their properties. Graphene-based supercapacitors are well researched due to interesting properties of graphene oxide (GO) and reduced graphene oxide (rGO). Among them, Wang et al. reported the synthesis of Ni(OH)₂ nanoparticles supported on graphene sheets – this new material showed a surprising capacitance value of 1335 F g⁻¹ at a current density of 2.8 A g⁻¹ with a retention of ~99% after 2000 charge/discharge cycles at 28.6 A g⁻¹. On the other hand, using another synthetic method and bare GO, Lee et al. produced nanoballs of a mesoporous graphene using chemical vapour deposition with a high specific area (508 m² g⁻¹) and this material exhibited a capacitance value of 206 F g⁻¹ with an excellent retention of 97% after 10k cycles. Although graphene has presented such interesting remarks, its synthesis
in high purity possesses some drawbacks e.g., multistep synthesis and hazardous waste generation that is highly acid and oxidant. In this context, the research for new graphene-like materials with similar properties and environmentally friendly has been one of the most important topics over the last few years.

It is also important to cite some works in which planar-like materials was used as supercapacitor active material. This kind of structures have shown an improved performance due to, among other factors, the interlayer intercalation. Besides, the enhanced operation life-time could be archived with the use of large molecules between the 2D structures of the material of interest.

Although g-C₃N₄ was discovered in 1834, research and application of its properties began only in 2006, with the detection of its photocatalytic properties for hydrogen evolution. Its structure is based on heptazine units, which exhibit different properties and reactivity depending on its synthesis conditions. g-C₃N₄ is a metal-free polymeric conjugated semiconductor that can be easily obtained by thermal polymerization of nitrogen rich precursors such as melamine, dicyandiamide, cyanamide, urea, thiourea, and ammonium thiocyanate. Each of these precursors leads to C₃N₄ samples with different levels of conjugation and density of defects that exhibit distinct electrochemical and photoelectrochemical properties. The simplest synthesis, guaranteeing good results despite its low yield (~3%), is the pyrolysis of urea/thiourea, which could be carried out at several temperatures (from 450 to 600 °C) in a conventional oven system in a non-inert atmosphere.

The high versatility of g-C₃N₄ is mainly due to its conjugated structure with sp² bonds between C and N atoms – like that of conducting polymers – which enables the easy modulation of its properties and 2D structural nature. While these nanostructured materials are stable under harsh conditions, being thermally (up to 600 °C in air) and chemically (under basic and acidic media) stable – unfortunately, carbon nitride shows poor solubility in most organic solvents, which hinders its processability. However, this material can be easily exfoliated forming stable dispersion and nanostructures with interesting properties compared to the bulk material; such as formation of very stable dispersions, higher specific surface area, and altered surface electronic structure by the formation of polar surface docking sites.

In addition, most of the exfoliation procedures still use highly acid solutions (e.g. concentrated sulphuric acid or hydrochloric acid) to obtain the delaminated material. Hence, it is recommended to replace these conventional and non-environmentally friendly procedures by procedures that employ green solvents by applying mechanical forces, for example, water-alcohol mixtures applied to sonication processes. It is important to mention that, due to the formation of quite stable suspensions obtained by the exfoliation in water-alcohol mixtures, it becomes possible to perform the deposition of C₃N₄ directly from the exfoliation solution on conductive substrates, increasing the range of applications of this material. Considering the exposed, graphitic carbon nitride (g-C₃N₄) is a potential and promising graphene-like material to replace the GO or rGO in the development of supercapacitors.

Likewise, the use of carbon nitride as a supercapacitor material has already been reported in the literature, although the properties of pristine material have not been thoroughly studied. As shown earlier, synthetic routes for the preparation of g-C₃N₄ are very important to the definition of its properties; in this way, some papers were chosen to this study, in which the pyrolysis of urea/thiourea were the most widely used. Therefore, Guan et al. studied the morphology influence on the supercapacitance of NiCo₂O₄ nanostructures anchored on C₃N₄ sheets. The C₃N₄ was obtained via thiourea pyrolysis for 3 h at 550 °C and the composites were obtained via a hydrothermal method using nickel and cobalt chlorides as precursors. The authors verified that nanoneedles have 69 F g⁻¹ at 2 A g⁻¹ as capacitance and a retention rate of 101% after one thousand cycles. On the other hand, with the same cycling number, the nanosheets structures exhibited 253 F g⁻¹ at 2 A g⁻¹, however with a retention of only about 64%. Another Ni–Co/C₃N₄ composite was studied by Li et al., in which, a highly porous carbon nitride was produced using sublimated sulphur in the thiourea pyrolysis and then, the composite was obtained in autoclave system after 12 h. This material exhibited optimum retention, maintaining 98% of its value of 206 F g⁻¹ capacitance at 1 A g⁻¹ after 1500 cycles.

Moreover, Shan et al. studied composites of MnO₂ on C₃N₄ pure and C₃N₄ doped with Na or K single atoms. The synthesis was also carried out using thiourea and the doping was performed by adding the KBr and NaBr salts together with the thiourea to pyrolysis. The authors found that the non-doped composite showed 96 F g⁻¹ of capacitance while the K and Na-doped showed values of 374 and 295 F g⁻¹, respectively, at 0.2 A g⁻¹. The lifetime of the materials was calculated after 1000 cycles at 1 A g⁻¹, and retentions were 59.1% for the non-doped, 95.2% for the K-doped and 93.7% for the Na-doped material.

An interesting work using melamine as precursor was described by Tahir et al., in which the authors synthesized tubular structures of C₃N₄. The nanostructure was obtained treating a melamine and ethylene glycol solution with HNO₃ before annealing it at 450 °C. A mixture of the obtained material and activated carbon was assembled on nickel foam and then electrochemically tested. The authors found a capacitance value of 233 F g⁻¹ and 204 F g⁻¹ for 0.2 A g⁻¹ and 0.5 A g⁻¹ respectively. The performance of capacitance retention after 1000 charge and discharge cycles was 90.9% and 89.2% for 0.2 A g⁻¹ and 0.5 A g⁻¹ respectively. Meanwhile, such results were compared with C₃N₄ bulk samples prepared under similar conditions, which showed worse performance.

On the other hand, pure carbon nitride has been also studied by Tahir et al. for this study the carbon nitride was produced from an ethanolic solution of melamine at 550 °C as graphitic carbon nitride nanofibers (GCNNF). This GCNNF showed a specific capacitance of 263.75 F g⁻¹ at 1 A g⁻¹ with a retention rate of 93.2% after 2000 charge/discharge cycles. With respect to this distinct citation regarding the properties of pure carbon nitride as supercapacitor there is a lack of important information about its durability to a greater number of charge and discharge cycles.
discharge cycles and their performance during them. In addition, the synthetic protocol is time consuming, needs higher temperature, and frequently needs a N₂ or Ar atmosphere. It is also important to point out that most of the reported studies are performed in strongly basic aqueous medium and this route might generate waste from the washing steps (OH⁻ concentration higher than 1.0 mol L⁻¹).

Considering these aspects, the present work aimed to evaluate the properties of pristine C₃N₄ obtained by the pyrolysis of urea and subsequently exfoliated using an eco-friendly approach. The exfoliated carbon nitride was used as an active layer in metal-free supercapacitors with high cyclability and fully characterized using the physical techniques XRD, FTIR, SEM, EDX, TGA, DSC and N₂ sorption in addition to the electrochemical techniques, cyclic voltammetry, charge/discharge curves and electrochemical impedance spectroscopy.

2 Experimental

2.1 Reactants and materials

All the chemicals used in this work were analytical grade and were used as received without further purification. Lithium perchlorate (LiClO₄) and acetonitrile (ACN) were purchased from Sigma-Aldrich (USA) and isopropanol and urea were purchased from Synth (Brazil). The ultrapure water was purified by an Milli-Q (Millipore) system.

2.2 Carbon nitride synthesis

The g-C₃N₄ was synthesized following the urea pyrolysis route.²⁷ The urea was triturated, and then the powder was placed in a wide and deep refractory bowl. The sample was heated at a rate of 10 °C min⁻¹ in air atmosphere, the pyrolysis occurred at 500 °C for 2 h and then the sample was cooled down to room temperature. As a result, a yellowish fine powder was obtained. To prepare the electrodes 10 mg of carbon nitride was dispersed in 5 mL of a mixture of water/isopropanol (2 : 1) in an ultrasonic bath for 3 h, to exfoliate the C₃N₄.¹⁹ Then, 60 μL of the dispersion was dropped on 1.0 cm² delimited area of an FTO (fluoride doped tin oxide) substrate and then dried at 60 °C for 2 h. The measurements of the substrate masses were accomplished before and after the deposition process to estimate the mass of the deposited film. Thus, the average mass of 0.49 ± 0.02 mg of deposited C₃N₄, and the measured masses were used to calculate the normalized properties of the material.

2.3 Electrochemical characterizations

The electrochemical measurements were performed using a PGSTAT 302 Autolab electrochemical system with FRA2.0 module monitored with NOVA 1.11 software. The measurements were carried out in LiClO₄ 1.0 mol L⁻¹ acetonitrile solution using a conventional electrochemical cell purged with N₂ during the processes. A pseudo reference electrode was used (Ag wire). The cyclic voltammetry (CV) was performed between 0.2 and 0.8 V at several scans rate (from 20 to 120 mV s⁻¹). The galvanostatic charge/discharge (CnD) curves were performed in the same potential window applying different currents (from 0.2 to 9.0 A g⁻¹). The aging of the material was studied by cycling the films using the CnD measurements at 3.0 A g⁻¹. The electrochemical impedance spectroscopy (EIS) data was obtained at open circuit potential (OCP) between 10 kHz and 100 mHz with perturbation of 10 mVrms; the data was fitted using the transmission line model. Both, CV and EIS measurements were taken before each 250 CnD cycles.

2.4 Physical characterizations

The electrode morphology characterization and elementary analysis were performed by Scanning Electron Microscopy (SEM) and EDX (Energy Dispersive X-ray spectrum) in a FEI Inspect microscope model F50 equipped with EDX detector. The crystalline structure was characterized using X-ray diffraction technique in an XRD-6000 Shimadzu X-Ray Diffractometer in step scan mode (2° min⁻¹) with CuKα 1.5406 Å. The chemical bonds structure was characterized in both Fourier-transformed infrared and diffuse reflectance method (FTIR-DRIFTS) using a Bruker EQUINOX 55 infrared spectrometer and Raman spectra using a Bruker RFS 100/S spectrometer using as excitation source a YAG:Nd laser (1064 nm). Additionally, aiming to investigate the purity of the obtained C₃N₄, Differential Scanning Calorimetry (DSC) and thermogravimetric analysis (TGA) were performed in TG/DSC analyser model STA 449 F3 Jupiter (Netzsch) equipment; a heating rate of 10 °C min⁻¹ in an open alumina crucible in an atmosphere of synthetic air (80% N₂ and 20% O₂) was used. Nitrogen adsorption/desorption isotherms were acquired using a Micromeritics ASAP 2010 instrument; the Brunauer–Emmett–Teller (BET) method was applied to obtain the specific surface area. Finally, the exfoliation effect over the C₃N₄ electronic structure was evaluated using Diffuse Reflectance to build a Kubelka–Munk plot, was used a Cary 5G spectrometer to acquire the reflectance diffuse data.

3 Results and discussion

After obtaining the g-C₃N₄ and its subsequently exfoliation, the characterizations were made to ensure that the material prepared was C₃N₄ free of urea impurities. In this way, Fig. 1a and b show the X-ray diffraction and the FTIR spectra of both bulk and exfoliated material, to demonstrate that the material was not altered by the exfoliation process, in which both XRD pattern and infrared spectra are consistent with those reported in the literature.¹⁶,²⁷,²⁸ In the XRD diffractogram (Fig. 1a), as expected, two diffraction peaks located at 13.1° and 27.5° confirm the carbon nitride crystalline structure.²⁷,²⁸ FTIR spectra (Fig. 1b) exhibited no change between exfoliated and bulk material. Both spectra show the fingerprint for the C₃N₄ bands assigned to the N–H stretching at 3190 cm⁻¹, bands from 1570 to 1620 cm⁻¹ and 1250 to 1430 cm⁻¹ assigned to the C–N and C=N stretching, respectively; and one intense and narrow band at 810 cm⁻¹ assigned to the C–N angular deformation in the heterocyclic structure.²⁹ The difference in the intensity and the separation in the broadband from 1110 to 1780 cm⁻¹ is attributed to the high conjugation degree of the C₃N₄ structure. Furthermore, the Urea XRD and FTIR spectrum is provided in...
ESI, Section S.I. 1,† in which comparing with results of the carbon nitride, it is not possible to observe the presence of peaks related to urea as contamination in both XRD and FTIR spectra. In addition, thermal analysis suggested a complete conversion of the urea precursor into carbon nitride material, as shown in Fig. S2.†

In the Raman spectra (Fig. 1c) is possible to see for both samples the D and G bands, as in graphene the D and G bands is related to the edge and basal planes respectively. So, in the exfoliated sample it is possible to observe a broadening of the peaks, this could be related to the loss of organization that existed when the C$_3$N$_4$ sheets were stacked, in addition the relative intensity between these two bands also underwent a change, as expected the G band became more intense due to the release of the basal planes.30,31 Fig. 1d show the Kubelka–Munk plot and the calculated bandgap energy for both samples, it was described in the literature that the exfoliation process leads to a slightly decrease of the band gap energy ($E_g$).18,19,32 Thus, although the DRX profile and the FTIR spectra did not show significant change, the Raman spectra and $E_g$ values evidenced the change suffered by carbon nitride after mechanical exfoliation.

Fig. 2 shows the morphology of the carbon nitride flakes deposited on FTO, in which the exfoliated sheets are very thin and transparent (inset image). Besides, the C$_3$N$_4$ presented a rough surface with the aspect of a crumpled paper-sheet, suggesting a high porosity in this material. Keeping in mind that the pseudocapacitance from the double-layer depends on the electrochemical active area and is proportional to the surface area, these characteristics are very important to achieving high specific capacitance. From the N$_2$ adsorption curve (using BET model) it was found that the material obtained in this work has 38.5 m$^2$ g$^{-1}$, compatible with the results found in the literature.16 Complete adsorption isotherms are provided in the ESI, Section S.I. 2.†

The capacitor properties were characterized using cyclic voltammetry (Fig. 3a) and charge/discharge curves (Fig. 3b), varying sweep velocity and specific current applied, respectively. The charge/discharge measurements were performed between the potential cut-off limits of 0.2 and 0.8 V, and the same potential window was used for the cyclic voltammetry scan. The specific capacitance was calculated from the slope of the linear region of the discharge curves and from the voltammetry, it was calculated using the oxidation charge, as proposed by Ramya
et al. Both specific capacitance as a function of the scan rate (Fig. 3c) and as a function of the specific current (Fig. 3d) decrease with the increase of the charge and discharge rate, which could mean that these processes are diffusion controlled, as expected for a redox supercapacitor. The specific capacitance retention calculated for the CV scan rate function was 68.9% and 54.4% for the CnD specific current function. Besides, the cyclic voltammetry does not exhibit any characteristic peak for oxidation/reduction processes in the potential window studied. In addition, the material also does not exhibit the standard rectangular shape of a capacitive behaviour, which could be also seen in the triangular-shape in the CnD curves. Additionally, there is a certain slope in the voltammogram, which suggests that the film has considerable resistivity. Taking into account

![Graphs and images from the document]
the C3N4 lamellar and porous structure, this resistivity and shape deviation is associated to a pseudo capacitance due to the redox transformations.\textsuperscript{34,15}

To evaluate the durability of the C3N4 film, the electrode was cycled 5000 times, in which at regular intervals, cyclic voltammetry and impedance spectroscopy data were collected, to obtain more insights regarding the aging of the film. Fig. 3 shows the changes in the CV, CnD curves and EIS data before and after 5000 cycles. The shape of CV profile remained the same even after the 5k cycles, although a small decrease in the current values (Fig. 4a) was observed and the same behaviour was noted in the CnD curves (Fig. 4a). From the first CnD cycle, the discharge process occurs slightly faster (from 20.6 s to 16.5 s), which leads to a small decrease in the capacitance value. Nevertheless, it is interesting to note that the charging time increased with the aging, leading to a lost in the coulombic efficiency.

Fig. 4c and d show important changes in the impedance data. First, there is no significant change in the system impedance at high frequency, suggesting that the inherent electrode processes are not modified due to the charge and discharge cycles. Otherwise, at low frequency region there is an increase in the impedance, suggesting that slower processes, such as ion intercalation, are slower after cycling. With respect to the system at constant time, in Fig. 3d it is possible to see a displacement to low frequency (from 37.1 Hz to 15.8 Hz), which means that the process to which it associates takes a longer time to occur, 36.4 ms more. This constant time could be associated with the ion intercalation process due to the charge and discharging scan that takes longer to happen after the 5k cycles.

From the Ragone chart, it is possible to find important values to measure the performance of a supercapacitor, namely, maximum specific energy and maximum specific power. Each point in the curve is given as the ratio between the energy and the power densities, characterizing the rate that a given amount of energy is supplied as a function of power. Straight diagonals that cross the isocurves indicate the operating time of the capacitor and its respective power and energy amount. These curves are very interesting because they provide a clear idea of the possible application of the studied device, since different uses require different combinations of power and energy.

Such curves can be estimated from the impedance data by applying a simple relation between the admittance and the disturbance that was applied in the system during data acquisition. Thus, as described by Kurzweil,\textsuperscript{36} the eqn (1) and the eqn (2) are used to calculate the specific energy and specific power, respectively:

\[
\text{Specific energy} : Q = \frac{-U^2}{Z \cdot Z'} \times \frac{1}{m} \quad (1)
\]

\[
\text{Specific power} : P = \frac{U^2}{Z \cdot Z'} \times \frac{1}{m} \quad (2)
\]

where, $U$ is the rms potential; $Z$ is the impedance modulus; $Z'$ is the real part of the impedance; $-Z''$ is the imaginary part of the impedance and $m$, the mass of active layer. Although, the Ragone chart is used for two-electrode devices to measure it performance, is described in some papers that it is possible to obtain important information from the three-electrodes configuration.\textsuperscript{37-41} Therefore, with this information, it is possible to obtain some important information about the system and then, obtain an idea of the final device performance.

In the light of the aforementioned, Fig. 5 shows the isocurves for the C3N4 before and after the 5000 charge and discharge cycles, in which both curves are expected for supercapacitors, although they show relatively low values of specific power compared to other types of devices.\textsuperscript{1} In the first applications, the material can deliver a maximum specific energy of 76.5 W h kg$^{-1}$ with a power of 11.9 W kg$^{-1}$; but for subsequent applications it can deliver 35.3 W h kg$^{-1}$ with a maximum power of 32.6 W kg$^{-1}$. Also, after cycling, the maximum specific energy that can be used decreases to 68.3 W h kg$^{-1}$ at a power of 10.9 W kg$^{-1}$ and supplying 31.5 W h kg$^{-1}$ with a maximum power of 28.9 W kg$^{-1}$. These results demonstrate that this device can deliver its maximum of energy with 3 times less power than maximum operating power or likewise, deliver half of its maximum energy with 3 times less power than maximum operating power.

Furthermore, in order to exemplify its properties, a capacitor made of 42.0 g of this electroactive material would be required to start a Toyota Brushless ACPM motor (Toyota Prius 2004).\textsuperscript{21,43}

In terms of specific energy, these values are similar to other reported C3N4 composites supercapacitors.\textsuperscript{21,44-46} It is important to mention that such works refer to complex materials and composites that have some metal, whereas the present work refers to a single material that is metal-free, which is a huge advantage in the current concerns about the environment. On the other hand, the specific power values are low when compared to the similar materials, such as graphene-based
materials and the CoS_{2}/g-C_{3}N_{4} composites studied by Jiang et al.\textsuperscript{47} However, it is important to mention that the delivery time at the maximum and minimum operating powers lies between 2 ms and 0.2 ms respectively, being quite reasonable for an organic and metal-free supercapacitor. Since the power information from that Ragone chart was obtained from the real part of the impedance data, this low specific power to the high charge-transfer resistance found for the electrode sample (2.29 kΩ), is assigned to the ion intercalation in the lamellar matrix of the carbon nitride.\textsuperscript{16,18}

Since the durability of a capacitor is as important as its stability, it was similarly evaluated the properties of the material during the CnD cycles. Thus, Fig. 6 shows the specific capacitance and coulombic efficiency over the 5k cycles. Initially, the capacitance value is 62.8 F g\textsuperscript{-1}, followed by a significant drop, after this initial drop, the capacitance remains constant during the cycles, showing a retention rate of 89.2% of the capacitance value (Fig. 6a), which is a quite impressive value for a pure material. As seen earlier, initially the loading time was slightly lower than the discharge time, reversing such a relationship with the successive CnD cycles. In such way, the coulombic efficiency at the beginning of the aging study was of 101.6% before 5000 cycles but this value drops to 95.4%, suggesting an initial change in the film structure and then being stabilized.

The electrochemical characterizations allowed evaluating the applicability of pure C_{3}N_{4} as an active layer in electrochemical capacitors. In addition, it is important to note that the material was obtained in a simple way and using few operations, which were required to it deposition over the electrode surface. The capacitance value and the high cyclability life-time observed in this study are compatible with the results already reported in the literature for composites with longer time-consuming preparations. In this context, these results suggest that pure C_{3}N_{4} is a quite promising organic supercapacitor material for energy storage purposes, being easily prepared, cheap, metal-free, and environmentally friendly.

Considering the above aspects, the synthesis of some composites causes the C_{3}N_{4} sheets flattening; thus, the addition of this second material does not compensate the properties lost because of C_{3}N_{4} sheets structural change, leading to a worsening of its properties. Likewise, some oxides addition could lead to the pore blockage, which in same way leads to a decrease in properties. Thus, it is important to note that this bare material showed a superior performance than other composites using g-C_{3}N_{4} as base material, as summarized in Table 1.

Such results reinforce the need for an appropriate study of materials in their pure form prior to evaluating such composites, since these composites might represent a cost

<table>
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<tr>
<th>Material</th>
<th>Capacitance/F g\textsuperscript{-1}</th>
<th>Retention/%</th>
<th>Cycles number</th>
<th>Ref.</th>
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<tr>
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<td>101</td>
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<td>64.0</td>
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<td>233</td>
<td>90.9</td>
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<td>PEDOT/g-C_{3}N\textsubscript{4} in Na\textsubscript{2}SO\textsubscript{4}</td>
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<td>96.5</td>
<td>1000</td>
<td>50</td>
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<td>Exfoliated bare C_{3}N\textsubscript{4}</td>
<td>113.7</td>
<td>89.3</td>
<td>5000</td>
<td>This work</td>
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Fig. 6 (a) specific capacitance and coulombic efficiency in function of charge/discharge cycles at 3.0 A g\textsuperscript{-1} (the inset contains the first charge/discharge cycles).
increasing in the development of new materials that may not be justified once there is a small improvement of their properties.

4 Conclusions

The properties of an electrode made only of exfoliated g-C3N4, which was easily synthesized via a simple method, from readily available material were evaluated. The material, tested in an organic medium with 0.1 M LiClO4 as electrolyte into the potential window of 0.2 to 0.8 V, showed a capacitance of 113.7 F g⁻¹ at 0.20 F g⁻¹ with impressive durability for a pristine material with a retention rate of 89.3% after 5000 charge and discharge cycles at 3.0 A g⁻¹. Moreover, the material showed a large amount of specific energy (76.5 W h kg⁻¹) at an operating power of 11.9 W kg⁻¹, which demonstrated a drop of only 89.3% due to electrochemical aging. Furthermore, it was noted that the performance of the pure carbon nitride was superior to other composites found in the literature. It is highlighted that these results are of great importance for understanding the inherent properties of carbon nitride to develop composites to increase their specific capacitance values while maintaining both their longer lifetime and their specific energy.

Conflicts of interest

There are no conflicts to declare.

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